

## Materials science aspects of quantum colour center creation in diamond by means of ion implantation

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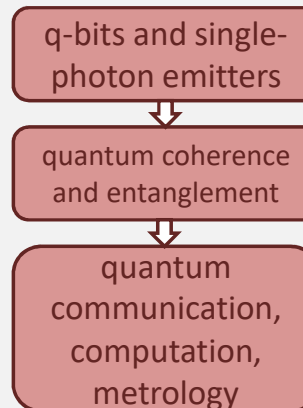
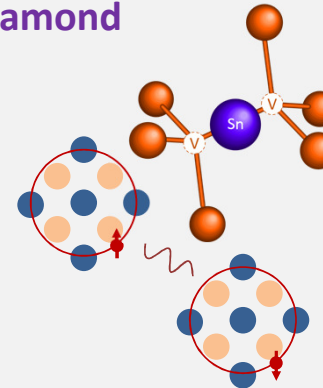
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- **Introduction: quantum centers suitable for studies with radioactive ion beams**
- **<sup>121</sup>SnV colour center in diamond**
- **Conclusions**

## Examples

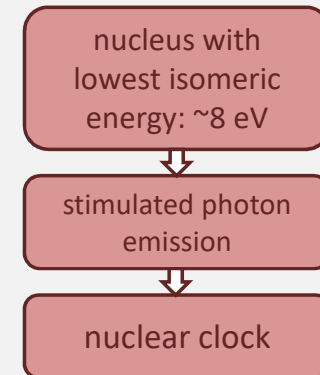
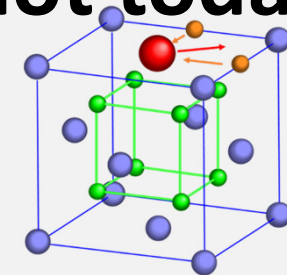
- Our research interest: impurities in solids which exhibit quantum properties useful for future applications: “quantum centers”
- General characteristics:
- Dilute impurity atoms embedded in a solid
- Quantum properties emerge from the electronic/nuclear interaction of the impurity with the crystal host
- Useful quantum properties are related to spin interactions, (stimulated) photon emission, coherence, entanglement, polarization of photons...
- Microscopic structure of centers determines their quantum properties
- Many such systems are produced by ion implantation

### Colour centers in diamond



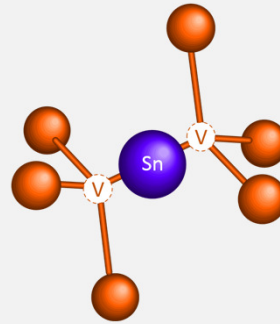
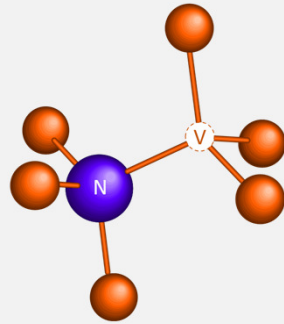
### <sup>229m</sup>Th nuclear isomer (~8 eV) in CaF<sub>2</sub> or MgF<sub>2</sub>

**not today**



- NV, SiV, GeV, SnV [1,2] and PbV colour centers in diamond are intensively investigated for their applications in processing and communication of quantum information and metrology.
- Two possible configurations for impurity-*vacancy* centers in diamond:

$C_{3v}$  “full-*vacancy*”,  
assumed for NV



$D_{3d}$  “split-*vacancy*” [3,4],  
assumed for group IV-*vacancy*: SiV, GeV, SnV, PbV

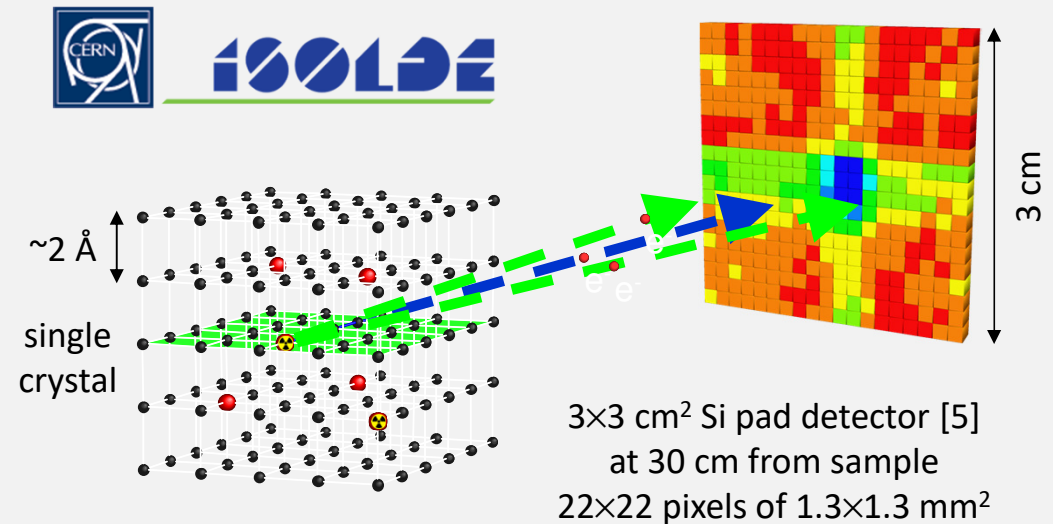
- Superior optical properties of the group-IV-*vacancy* centers are to a large extent a consequence of their  $D_{3d}$  inversion (mirror) symmetry.
- Group IV-*vacancy* centers are commonly produced by ion implantation.
- **How to optimize implantation conditions in order to achieve unperturbed split-*vacancy* configurations?**
- Emission channeling lattice location experiments are uniquely suited to study this problem.

**This talk!**

[1] D. Tchernij, ... J. Forneris, *et al.*, ACS Photonics 4 (2017) 2580  
 [2] T. Iwasaki, ... P. Syushev, *et al.*, Phys. Rev. Lett. 119 (2017) 253601

[3] J.P. Goss *et al.*, Phys. Rev. Lett. 77 (1996) 3041  
 [4] J.P. Goss *et al.*, Phys. Rev. B. 72 (2005) 035214

- Radioactive  $^{121}\text{Sn}$  ( $t_{1/2}=27$  h) probe atoms are produced at CERN's ISOLDE on-line isotope separator facility.
- 60 keV ion implanted ( $2 \times 10^{12} \text{ cm}^{-2}$ ) into diamond, measured RT as-implanted and 920°C annealed
- Position- and energy sensitive detector [5] is used to detect emission channeling [6] effects of  $\beta^-$  decay particles from  $^{121}\text{Sn}$  in the vicinity of major crystallographic directions.



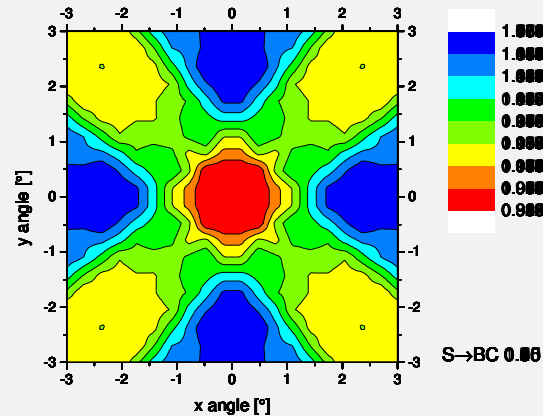
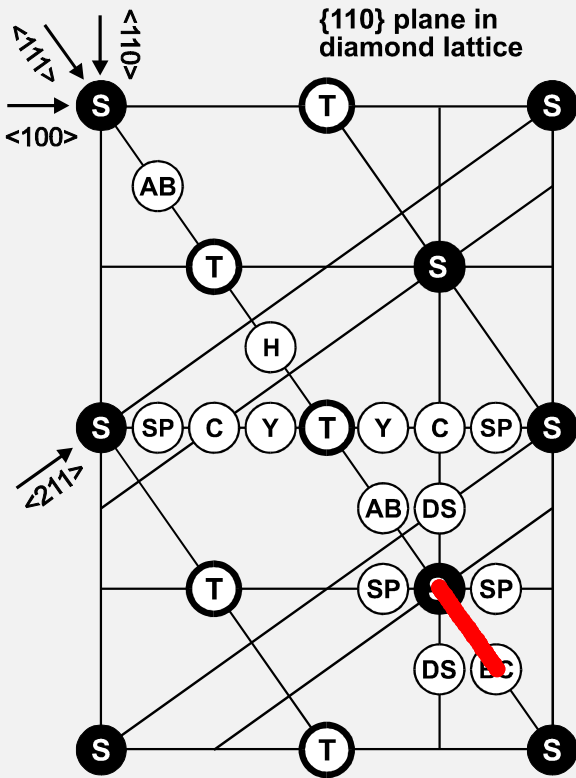
Angular dependent  $\beta^-$  emission patterns characterize the lattice site distribution of the  $^{121}\text{Sn}$  emitter atoms.

[5] U. Wahl *et al.*, Nucl. Instr. Meth. A 524 (2004) 245

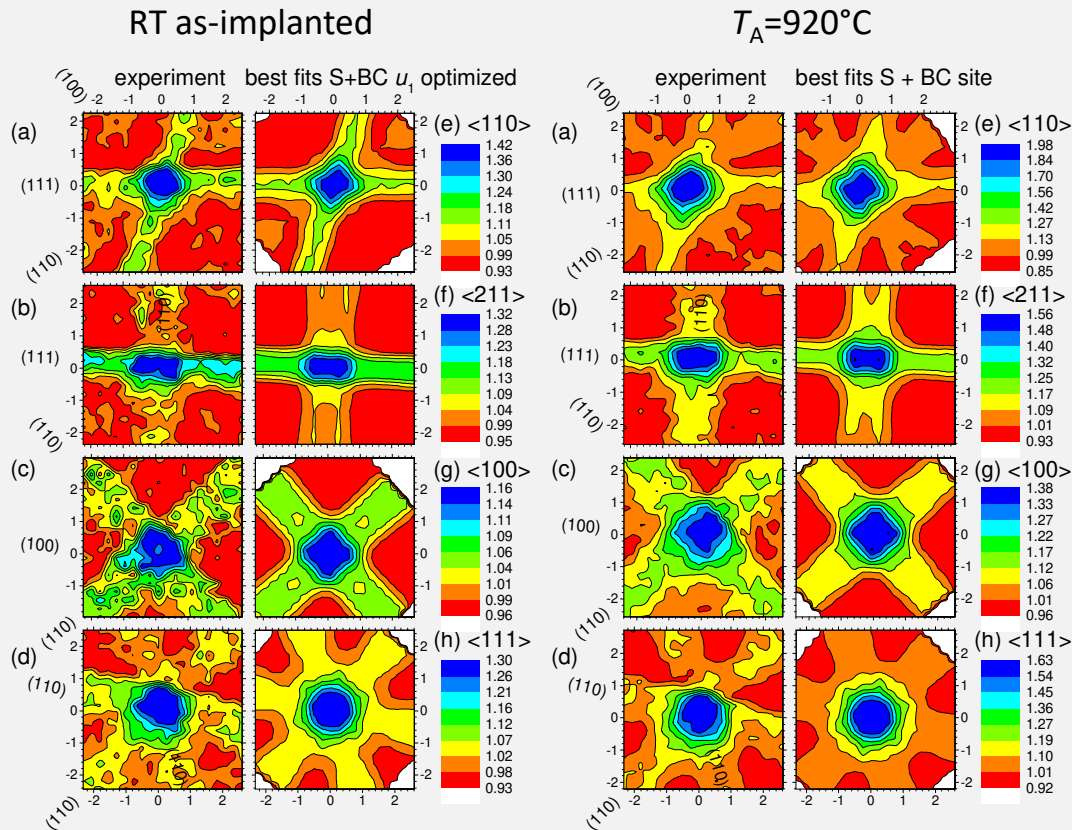
[6] H. Hofsäss, G. Lindner, Phys. Rep. 201 (1991) 121

- $\beta^-$  angular emission yield patterns from  $^{121}\text{Sn}$  are calculated for  $\sim 250$  lattice sites in the diamond unit cell using the "many-beam" [6,7] approach.
- Anisotropy and contours of patterns change with position of  $^{121}\text{Sn}$  in the lattice, e.g. the  $\langle 100 \rangle$  pattern when moving from S to BC sites:

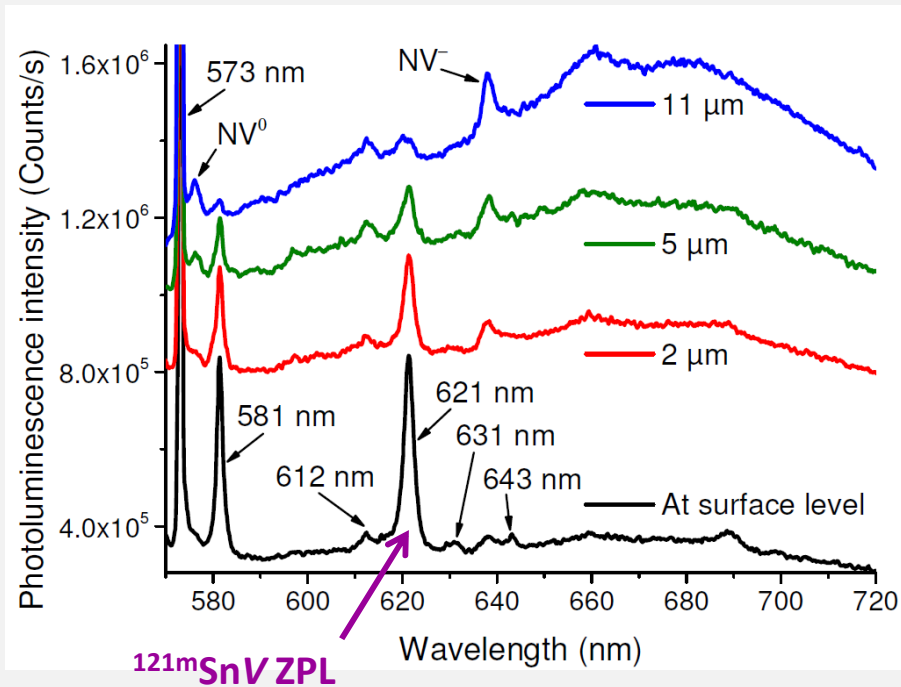
high-symmetric sites in diamond



[6] H. Hofsäss, G. Lindner, Phys. Rep. 201 (1991) 121  
 [7] U. Wahl *et al.*, Hyperf. Interactions (2000) 129 349



- Strong channeling effects along all axial and planar directions indicate that  $^{121}\text{Sn}$  substitutional sites must be involved.
- 920°C annealing ~doubles the maximum yield ( $\beta^-$  anisotropy) of all patterns. A considerable fraction is found on BC sites (split-vacancy configuration).
- RT as-implanted: best fits obtained for 63% S with  $u_1=0.18 \text{ \AA}$   
41% BC with  $u_1=0.11 \text{ \AA}$
- $T_A=920^\circ\text{C}$ : best fits obtained for 79% ideal S with  $u_1=0.034 \text{ \AA}$   
32% ideal BC with  $u_1=0.034 \text{ \AA}$



- Same sample as used for EC also contains the long-lived isomer  $^{121m}\text{Sn}$  ( $t_{1/2}=55$  y)
- Photo Luminescence (PL) excitation by 532 nm laser 1 mW

- 920°C annealed: sharp (FWHM 2.3 nm) zero phonon line (ZPL) from  $\text{SnV}^-$  at 621 nm [1,2] near the surface
- **Our sample showed the lowest ensemble FWHM at RT so far reported in the literature.**
- Recently published: U. Wahl *et al.*, Phys. Rev. Lett. 125 (2020) 045301/1-7

[1] D. Tchernij, ... J. Forneris, *et al.*, ACS Photonics 4 (2017) 2580

[2] T. Iwasaki, ... P. Syushev, *et al.*, Phys. Rev. Lett. 119 (2017) 253601

| Isotope           | $t_{1/2}$ | yield [ions/ $\mu\text{C}$ ]        | target + ion source                 |
|-------------------|-----------|-------------------------------------|-------------------------------------|
| <sup>31</sup> Si  | 157 min   | <sup>31</sup> Al: $2.5 \times 10^5$ | UC <sub>x</sub> + Al RILIS          |
| <sup>75</sup> Ge  | 82.8 min  | <sup>75</sup> Ga: $3 \times 10^7$   | UC <sub>x</sub> + Ga RILIS          |
| <sup>121</sup> Sn | 27.1 h    | $1 \times 10^8$                     | UC <sub>x</sub> + Sn RILIS          |
| <sup>209</sup> Pb | 3.25 h    | ?                                   | UC <sub>x</sub> + Pb RILIS + LIST?  |
| <sup>27</sup> Mg  | 9.46 min  | $1 \times 10^7$                     | Ti + Mg RILIS                       |
| <sup>45</sup> Ca  | 164 d     | <sup>45</sup> K: $1 \times 10^7$    | UC <sub>x</sub> - W                 |
| <sup>89</sup> Sr  | 50.5 d    | <sup>89</sup> Rb: $5 \times 10^9$   | UC <sub>x</sub> - W                 |
| <sup>6</sup> He   | 807 ms    | $5 \times 10^7$                     | UC <sub>x</sub> or BeO              |
| <sup>23</sup> Ne  | 37.2 s    | $1.6 \times 10^6$                   | UC <sub>x</sub> plasma              |
| <sup>41</sup> Ar  | 109 min   | $3.2 \times 10^7$                   | TiO <sub>2</sub> or UC <sub>x</sub> |
| <sup>87</sup> Kr  | 76.3 min  | $2 \times 10^8$ - $2 \times 10^9$   | UC <sub>x</sub> or PbBi             |
| <sup>133</sup> Xe | 5.24 d    | $6 \times 10^7$                     | PbBi plasma                         |
| <sup>135</sup> Xe | 9.14 h    | $1.5 \times 10^8$                   | ThC plasma                          |

- IS668 = “Quantum colour centers in diamond studied by emission channeling with short-lived isotopes (EC-SLI) and radiotracer photoluminescence”
- 20×8h shifts approved, first successful run on <sup>27</sup>Mg, <sup>45</sup>Ca, <sup>89</sup>Sr in diamond 6.-9.7.2021
- **Isotopes in red are also suitable for radiotracer PL.**
- Participating institutes:
  - C<sup>2</sup>TN, IST (Portugal)
  - QSP, KU Leuven (Belgium)
  - Universidade de Aveiro (Portugal)
  - University of Torino (Italy)
  - University of Warwick (UK)
  - CERN



- Diamond:
  - Lino Pereira, André Vantomme (Quantum Solid State Physics , KU Leuven, Belgium)
  - Vítor Amaral (CICECO, Universidade de Aveiro, Portugal)
  - Miloš Nesládek (Hasselt University, Belgium)
  - Karl Johnston (CERN, Geneva, Switzerland)
  - Ben Green (University of Warwick, UK)
  - Petr Syushev (group of F. Jelezko, University of Ulm, Germany)
  - Jacopo Forneris (University of Turin, Italy)
  - Ádám Gali (Wigner Research Center, Budapest, Hungary)
  - Gerald Auböck (Silicon Austria Labs)
- Quantera  
application on  
Quantum  
Repeaters based  
on SnV, PbV**
- <sup>229m</sup>Th:
  - Lino Pereira, André Vantomme (Quantum Solid State Physics, KU Leuven, Belgium)
  - Piet van Duppen (Instituut voor Kern- en Stralingsfysica, KU Leuven, Belgium)
  - Thorsten Schumm (Atominstitut, TU Wien, Austria)

- Emission channeling offers unique opportunities for structural studies of quantum colour center formation in diamond.
- First direct structural evidence and quantification for implanted  $^{121}\text{Sn}$  in the SnV “split-vacancy” configuration (surprisingly high yield of ~30%)
- PL signature of  $^{121\text{m}}\text{SnV}^-$  detected: sharp ZPL at 621 nm
- Besides  $^{121}\text{Sn}$ , beam time is also granted for further studies of other colour centers in diamond, using emission channeling and radiotracer PL.